

Single N-channel MOSFET

ELM58904A-S

<http://www.elm-tech.com>

■General description

ELM58904A-S uses advanced trench technology to provide excellent $R_{ds(on)}$, low gate charge and low gate threshold voltage.

■Features

- $V_{ds}=30V$
- $I_d=5.6A$
- $R_{ds(on)} = 72m\Omega$ ($V_{gs}=10V$)
- $R_{ds(on)} = 95m\Omega$ ($V_{gs}=4.5V$)

■Maximum absolute ratings

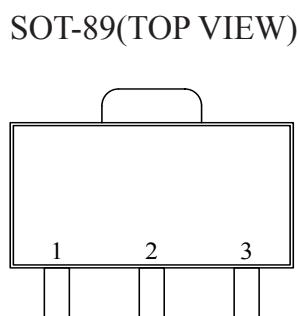
$T_a=25^{\circ}C$. Unless otherwise noted.

Parameter	Symbol	Limit	Unit
Drain-source voltage	V_{ds}	30	V
Gate-source voltage	V_{gs}	± 20	V
Continuous drain current($T_j=150^{\circ}C$)	I_d	5.6	A
		3.6	
Pulsed drain current	I_{dm}	10	A
Power dissipation	P_d	1.45	W
		0.60	
Junction and storage temperature range	T_j, T_{stg}	- 55 to 150	$^{\circ}C$

■Thermal characteristics

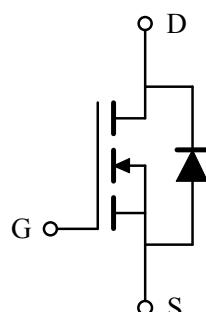
Parameter	Symbol	Typ.	Max.	Unit
Thermal resistance junction-to-ambient	$R_{\theta ja}$		120	$^{\circ}C/W$

■Pin configuration



Pin No.	Pin name
1	GATE
2	DRAIN
3	SOURCE

■Circuit

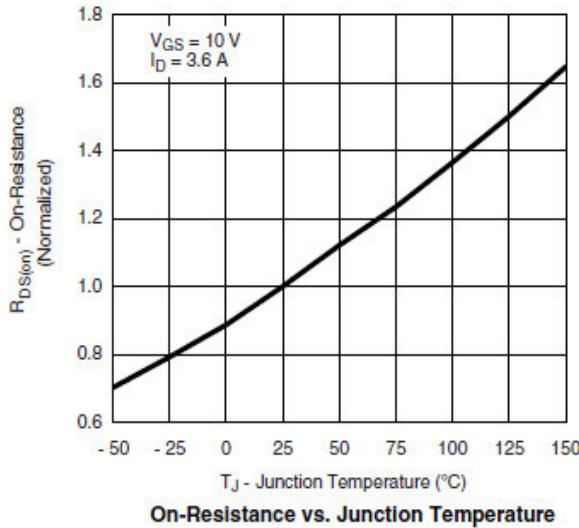
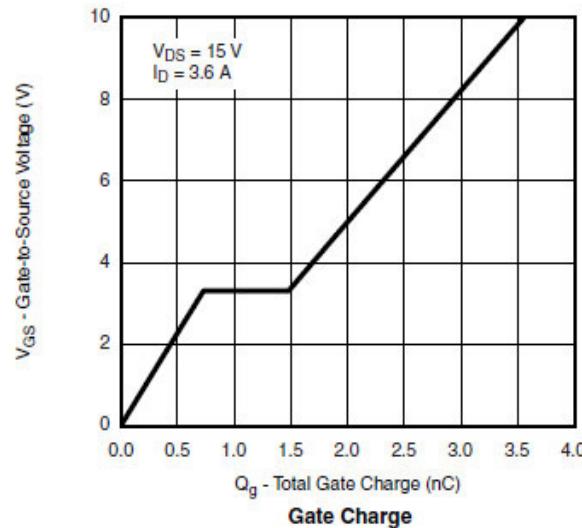
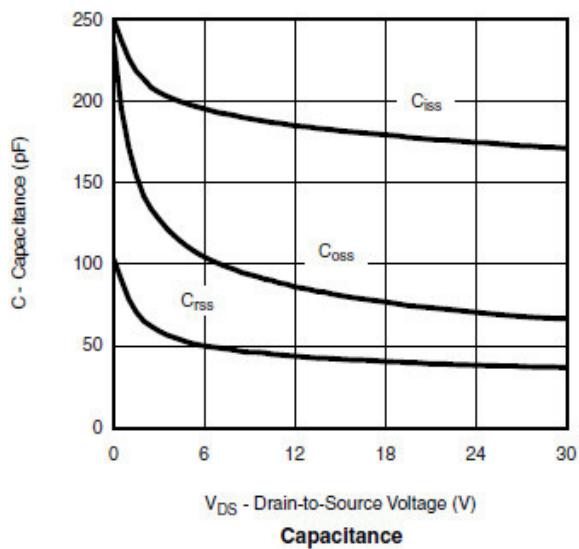
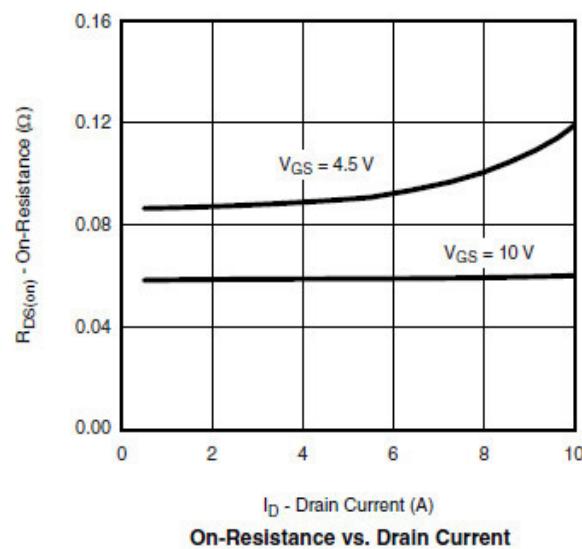
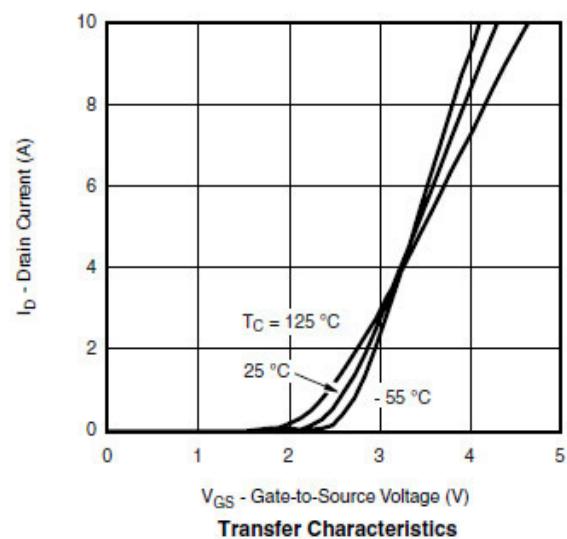
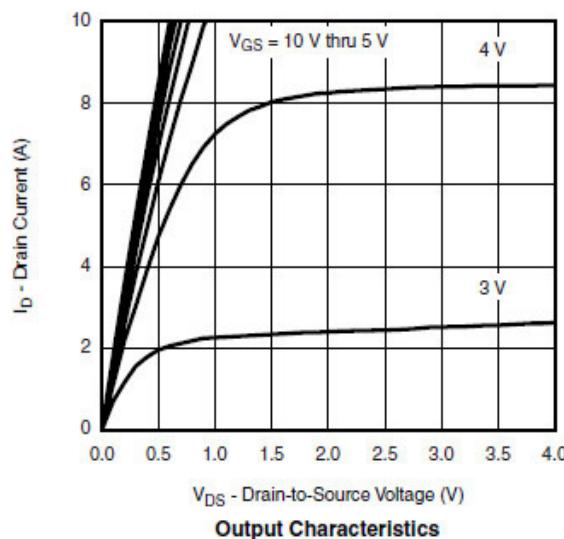


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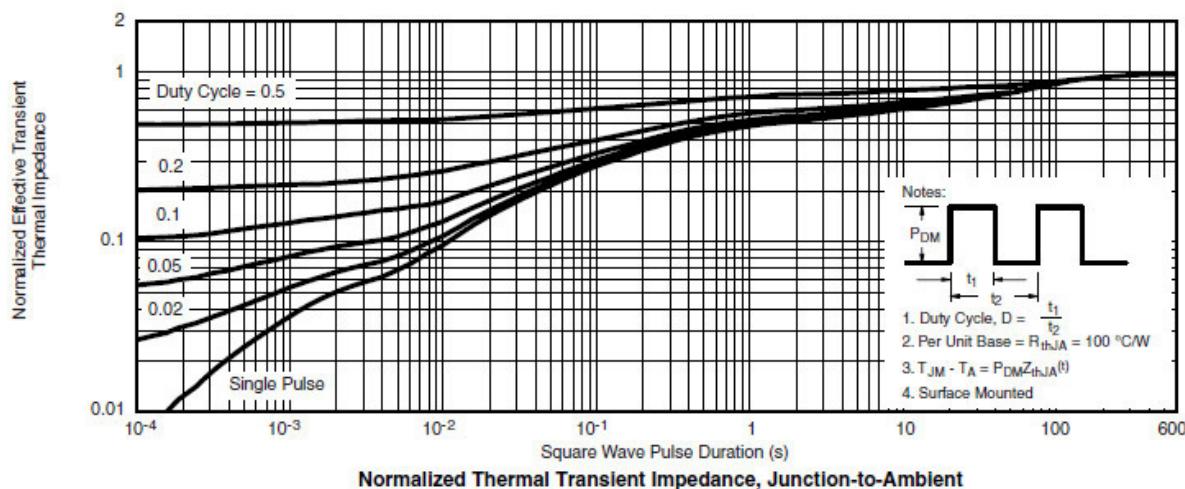
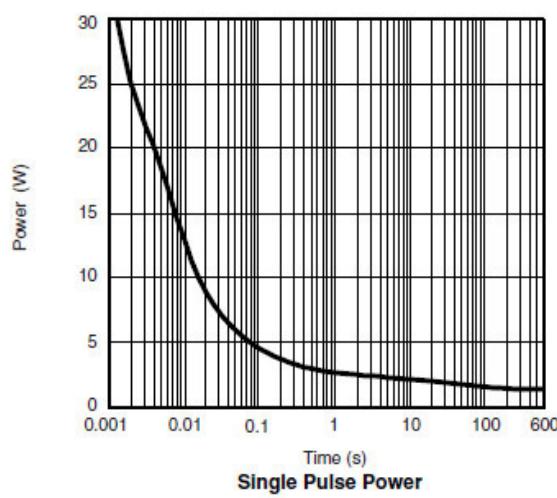
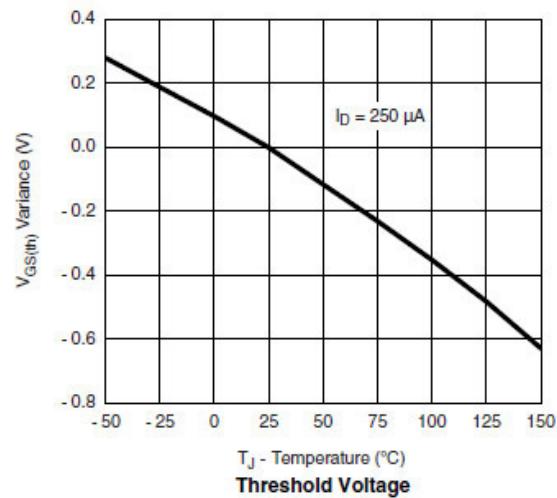
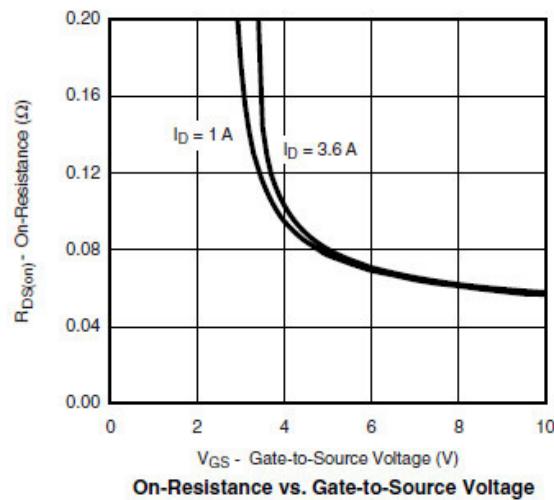
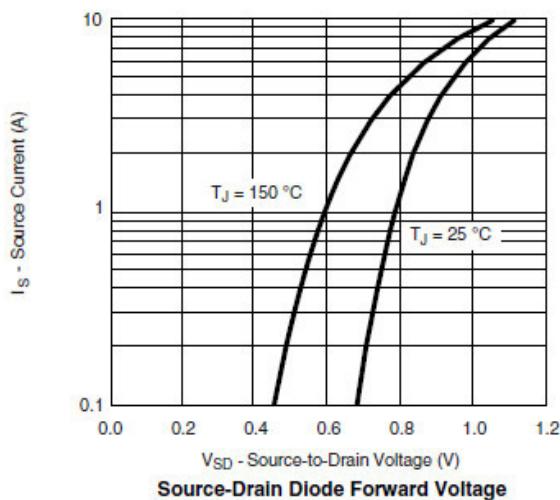
■ Typical electrical and thermal characteristics



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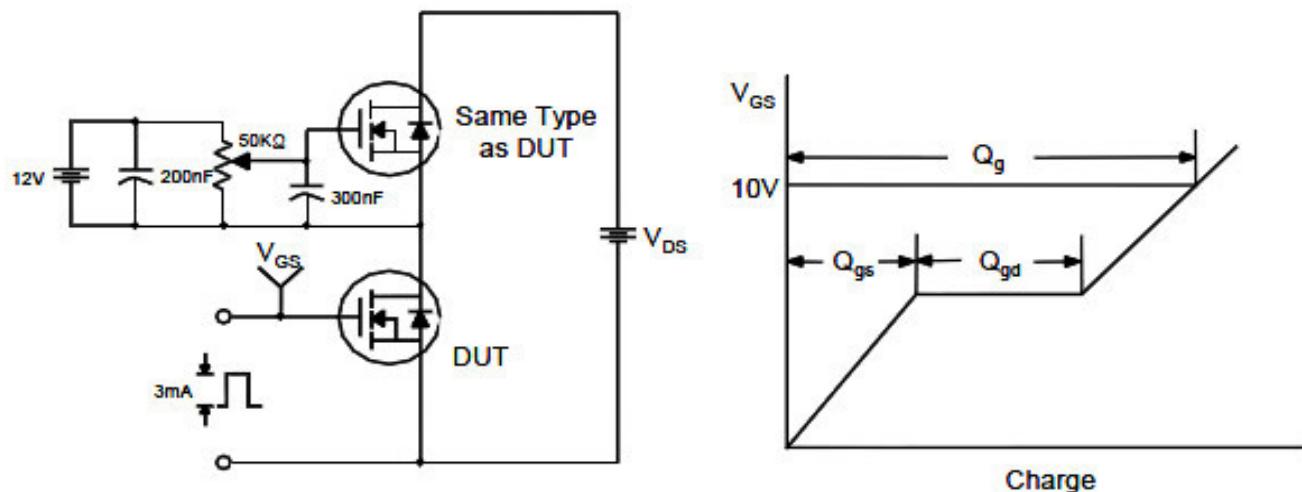
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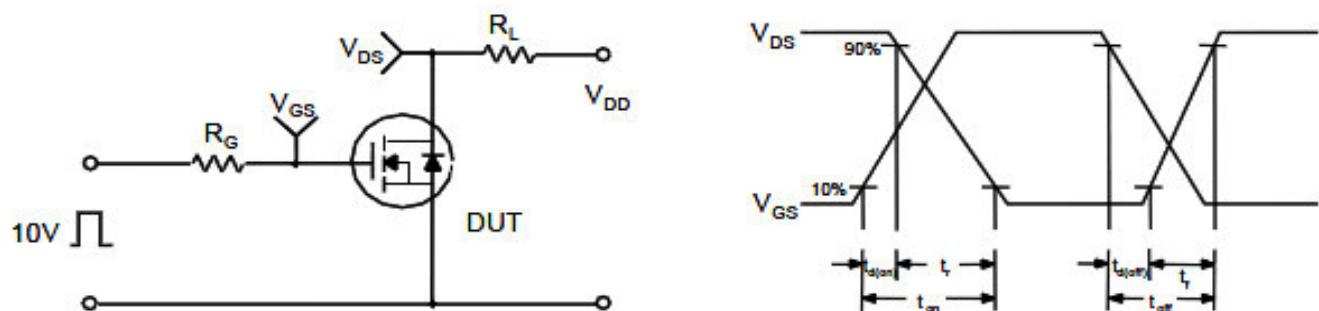
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■ Test circuit and waveform

Gate Charge Test Circuit & Waveform



Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching Test Circuit & Waveforms

